

2STX2220

High Gain Low Voltage PNP Power Transistor

General features

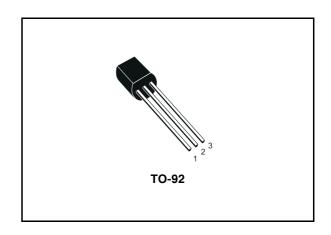
- Very low Collector to Emitter saturation voltage
- D.C. Current gain, h_{FE} >100
- 1.5 A continuous collector current
- In compliance with the 2002/93/EC European Directive

Description

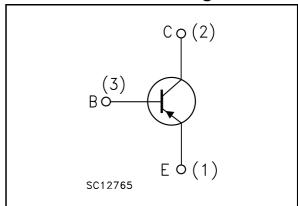
The device in a PNP transistor manufactured using new "PB-HDC" (Power Bipolar High Density Current) technology. The resulting transistor shows exceptional high gain performances coupled with very low saturation voltage.

Applications

- Power management in portable equipment
- Switching regulator in battery charger applications



Internal schematic diagram



Order codes

Part Number	Marking	Package	Packing
2STX2220	X2220	TO-92	Bulk

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2STX2220 Electrical ratings

1 Electrical ratings

Table 1. Absolute maximum rating

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-base voltage (I _E = 0)	-20	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	-20	V
V _{EBO}	Emitter-base voltage (I _C = 0)	-5	V
I _C	Collector current	-1.5	Α
I _{CM}	Collector peak current (t _P < 5ms)	-3	Α
Ι _Β	Base current	-0.1	Α
I _{BM}	Base peak current (t _P < 5ms)	-0.2	Α
P _{tot}	Total dissipation at T _{amb} = 25°C	0.9	W
T _{stg}	Storage temperature	-65 to 150	°C
TJ	Max. operating junction temperature	150	°C

Table 2. Thermal data

Symbol	Parameter	Value	Unit
R _{thj-case}	Thermal resistance junction-case max	44.6	°C/W
R _{thj-amb}	Thermal resistance junction-amb max	139	°C/W

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Electrical characteristics 2STX2220

2 Electrical characteristics

 $(T_{case} = 25^{\circ}C \text{ unless otherwise specified})$

Table 3. Electrical characteristics

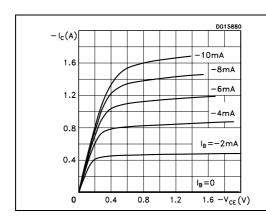
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector cut-off current (I _E =0)	V _{CB} = -20V			-0.1	μА
I _{EBO}	Emitter cut-off current (I _C =0)	V _{EB} = -5V			-0.1	μА
V _{(BR)CEO} (2)	Collector-emitter breakdown voltage (I _B = 0)	I _C = -10mA	-20			V
V _{(BR)EBO}	Emitter-base breakdown voltage (I _C = 0)	I _E = -100μA	-5			V
V _{CE(sat)} (2)	Collector-emitter saturation voltage	$I_C = -0.5A$ $I_B = -50mA$ $I_C = -1.5A$ $I_B = -150mA$			-0.25 -0.45	V V
V _{BE(sat)} (2)	Base-emitter saturation voltage	$I_C = -0.5A$ $I_B = -50mA$ $I_C = -1.5A$ $I_B = -150mA$			-1 -1.1	V V
V _{BE(on)} (2)	Base-emitter on voltage	$I_C = -1A$ $V_{CE} = -2V$			-1	V
h _{FE} ⁽²⁾	DC current gain	$\begin{split} & I_{C} = -100 \text{mA} & V_{CE} = -2V \\ & I_{C} = -500 \text{mA} & V_{CE} = -2V \\ & I_{C} = -1.5 \text{A} & V_{CE} = -2V \\ & I_{C} = -3 \text{A} & V_{CE} = -2V \end{split}$	200 170 120 75		600	
C _{CBO}	Collector-base capacitance	$I_E = 0$ $V_{CB} = -10V$ f = 1MHz		30		pF
t _{on} t _{off}	Resistive load Turn-on time Turn-off time	$I_C = -1.5A$ $V_{CC} = -10V$ $I_{B1} = -I_{B2} = -150mA$		60 250		ns ns

Note (2) Pulsed duration = 300 μ s, duty cycle \leq 1.5%

2.1 Electrical characteristics (curves)

Figure 1. Output characteristics

Figure 2. DC current gain



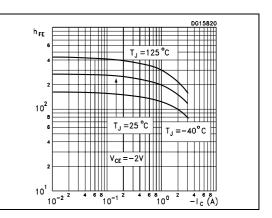
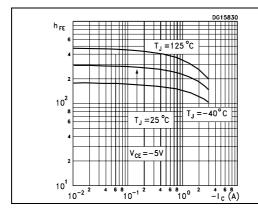


Figure 3. DC current gain

Figure 4. Collector-emitter saturation voltage



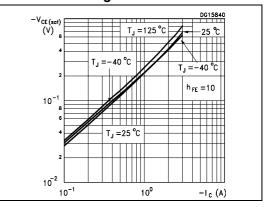
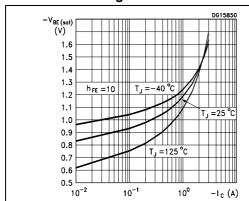
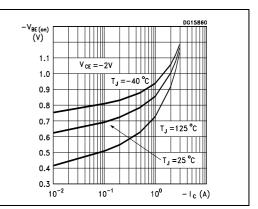


Figure 5. Base-emitter saturation voltage

Figure 6. Base-emitter on voltage





Electrical characteristics 2STX2220

Figure 7. Capacitance curves

Figure 8. Switching time resistive load

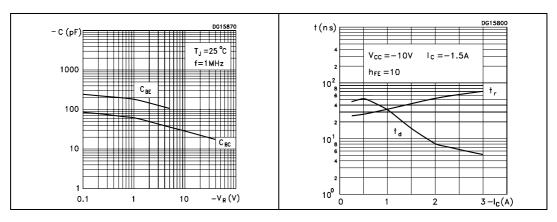
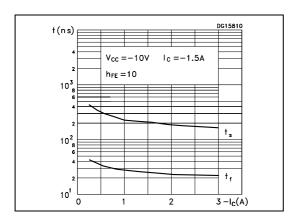
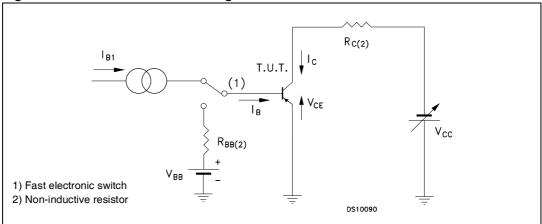


Figure 9. Switching time resistive load



2.2 Test circuits

Figure 10. Resistive load switching test circuit



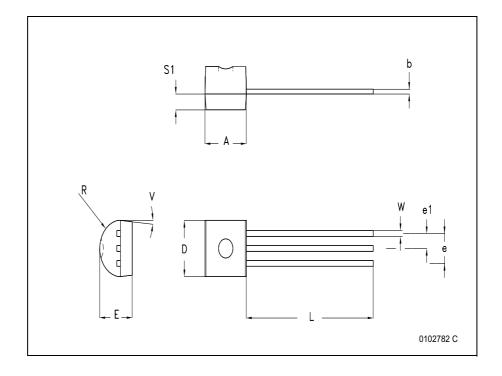
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3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

TO-92 BULK SHIPMENT MECHANICAL DATA

D.114	mm.				
DIM.	MIN.	ТҮР	MAX.		
А	4.32		4.95		
b	0.36		0.51		
D	4.45		4.95		
Е	3.30		3.94		
е	2.41		2.67		
e1	1.14		1.40		
L	12.70		15.49		
R	2.16		2.41		
S1	0.92		1.52		
W	0.41		0.56		
V		5 °			



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Revision history 2STX2220

4 Revision history

Table 4. Revision history

Date	Revision	Changes
19-Jun-2006	1	Initial release.
25-Sep-2006	2	New maturity code.

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